MJ2955 (See 2N3055) MJ2955A (See 2N3055A)

Medium-Power Complementary Silicon Transistors

 \ldots for use as output devices in complementary general purpose amplifier applications.

- High DC Current Gain hFE = 4000 (Typ) @ IC = 5.0 Adc
- Monolithic Construction with Built-in Base-Emitter Shunt Resistors

MAXIMUM RATINGS

Rating	Symbol	MJ2500 MJ3000	MJ2501 MJ3001	Unit
Collector-Emitter Voltage	V _{CEO}	60	80	Vdc
Collector-Base Voltage	V _{CB}	60 80		Vdc
Emitter–Base Voltage	V _{EB}	5.0		Vdc
Collector Current	IC	10		Adc
Base Current	lΒ	0.2		Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	150 0.857		Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{Stg}	-55 to +200		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θJC	1.17	°C/W

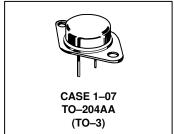
PNP **MJ2500**

MJ2501* MJ3000

MJ3001³

*Motorola Preferred Device

10 AMPERE
DARLINGTON
POWER TRANSISTORS
COMPLEMENTARY
SILICON
60-80 VOLTS
150 WATTS



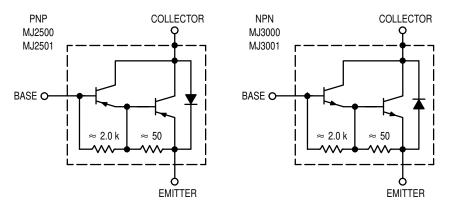


Figure 1. Darlington Circuit Schematic

Preferred devices are Motorola recommended choices for future use and best overall value.

REV 7



ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					•
Collector Emitter Breakdown Voltage ⁽¹⁾ (I _C = 100 mAdc, I _B = 0)	MJ2500, MJ3000 MJ2501, MJ3001	V _(BR) CEO	60 80		Vdc
Collector–Emitter Leakage Current (VEB = 60 Vdc, R _{BE} = 1.0 k ohm) (VEB = 80 Vdc, R _{BE} = 1.0 k ohm) (VEB = 60 Vdc, R _{BE} = 1.0 k ohm, T _C = 150° C) (VEB = 80 Vdc, R _{BE} = 1.0 k ohm, T _C = 150° C)	MJ2500, MJ3000 MJ2501, MJ3001 MJ2500, MJ3000 MJ2501, MJ3001	ICER	 - -	1.0 1.0 5.0 5.0	mAdc
Emitter Cutoff Current (VBE = 5.0 Vdc, IC = 0)		I _{EBO}	_	2.0	mAdc
Collector Emitter Leakage Current $(V_{CE} = 30 \text{ Vdc}, I_B = 0)$ $(V_{CE} = 40 \text{ Vdc}, I_B = 0)$	MJ2500, MJ3000 MJ2501, MJ3001	ICEO	_	1.0 1.0	mAdc
ON CHARACTERISTICS ⁽¹⁾					
DC Current Gain (I _C = 5.0 Adc, V _{CE} = 3.0 Vdc)		hFE	1000	_	_
Collector–Emitter Saturation Voltage ($I_C = 5.0 \text{ Adc}$, $I_B = 20 \text{ mAdc}$) ($I_C = 10 \text{ Adc}$, $I_B = 50 \text{ mAdc}$)		V _{CE(sat)}	_	2.0 4.0	Vdc

Base Emitter Voltage (I_C = 5.0 Adc, V_{CE} = 3.0 Vdc) (1)Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

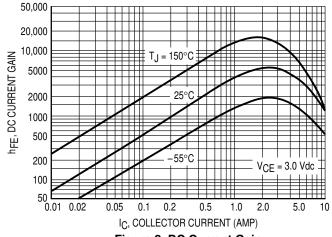


Figure 2. DC Current Gain

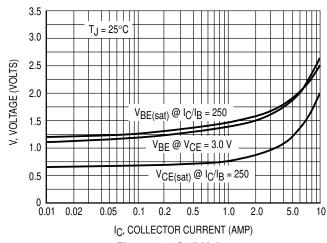
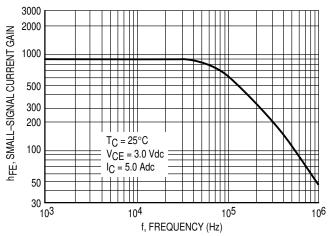


Figure 4. "On" Voltages

There are two limitations on the power handling ability of a transistor: junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; e.g., the transistor must not be subjected to greater dissipation



3.0

Vdc

V_{BE(on)}

Figure 3. Small-Signal Current Gain

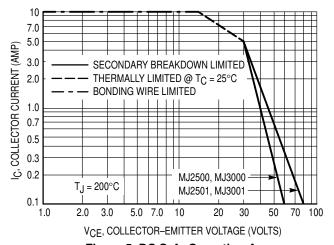
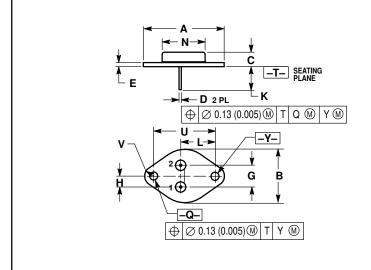


Figure 5. DC Safe Operating Area

than the curves indicate.

At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

PACKAGE DIMENSIONS



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	1.550 REF		39.37 REF		
В	-	1.050		26.67	
С	0.250	0.335	6.35	8.51	
D	0.038	0.043	0.97	1.09	
E	0.055	0.070	1.40	1.77	
G	0.430 BSC		10.92 BSC		
Н	0.215 BSC		5.46 BSC		
K	0.440	0.480	11.18	12.19	
L	0.665	BSC	16.89 BSC		
N		0.830		21.08	
Q	0.151	0.165	3.84	4.19	
U	1.187 BSC		30.15 BSC		
٧	0.131	0.188	3.33	4.77	

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR

CASE 1-07 TO-204AA (TO-3) ISSUE Z

MJ2500 MJ2501 MJ3000 MJ3001

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